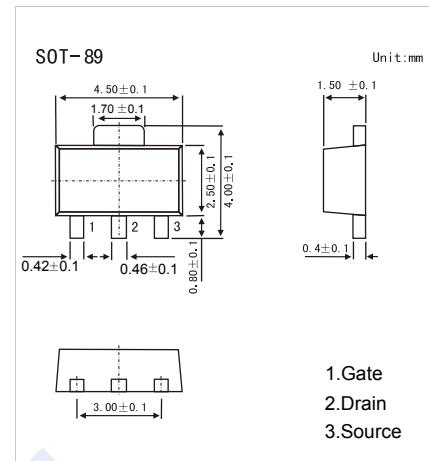
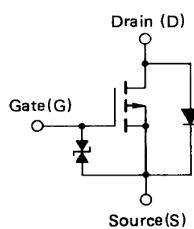


## P-Channel MOSFET

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#### ■ Features

- $V_{DS} (V) = -100V$
- $I_D = -0.5 A$
- $R_{DS(ON)} < 4.2 \Omega$  ( $V_{GS} = -10V$ )
- $R_{DS(ON)} < 5 \Omega$  ( $V_{GS} = -4V$ )



#### ■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	-100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current	$I_D$	-0.5	A
Pulsed Drain Current (Note.1)	$I_{DM}$	-1	
Power Dissipation	$P_D$	2	W
Junction Temperature	$T_J$	150	$^\circ C$
Junction Storage Temperature Range	$T_{stg}$	-55 to 150	

Note.1:  $PW \leq 10$  ms, duty cycle  $\leq 50\%$

#### ■ Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{DSS}$	$I_D = -250 \mu A, V_{GS} = 0V$	-100			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -100V, V_{GS} = 0V$			-10	$\mu A$
Gate-Body leakage current	$I_{GS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$			$\pm 10$	$\mu A$
Gate to Source Cutoff Voltage	$V_{GS(off)}$	$V_{GS} = -10V, I_D = -1mA$	-1		-3	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = -10V, I_D = -0.3A$			4.2	$\Omega$
		$V_{GS} = -4V, I_D = -0.3A$			5	
Forward Transconductance	$g_{FS}$	$V_{DS} = -5V, I_D = -0.3A$	0.4	0.5		S
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = -10V, f = 1MHz$		165		$pF$
Output Capacitance	$C_{oss}$			75		
Reverse Transfer Capacitance	$C_{rss}$			13		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS(on)} = -4V, I_D = -0.3A, R_L = 1.5 \Omega, R_G = 10 \Omega, V_{DD} = -5V$		110		$ns$
Turn-On Rise Time	$t_r$			320		
Turn-Off Delay Time	$t_{d(off)}$			100		
Turn-Off Fall Time	$t_f$			130		

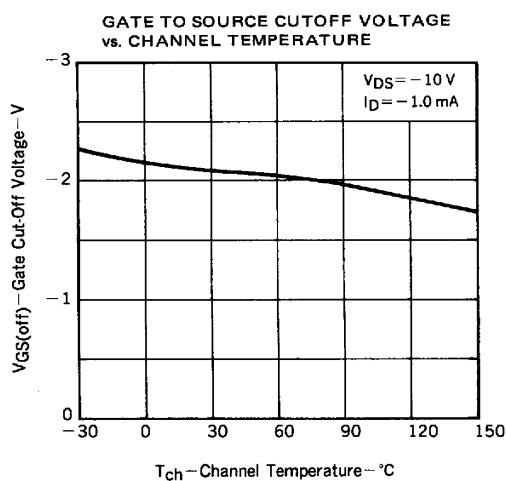
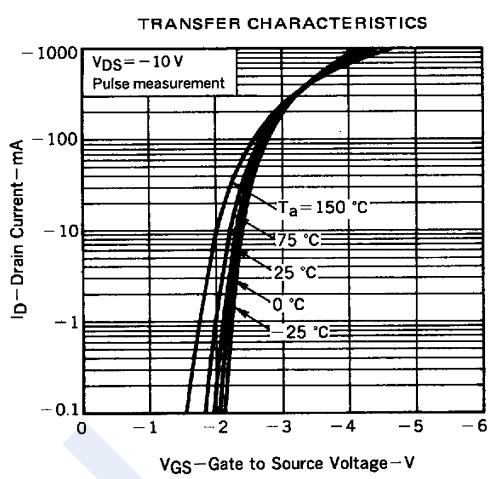
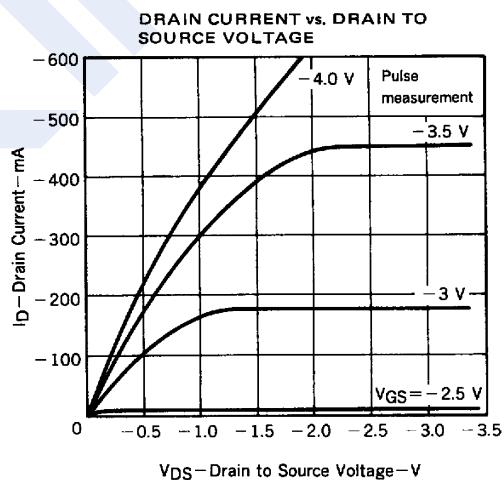
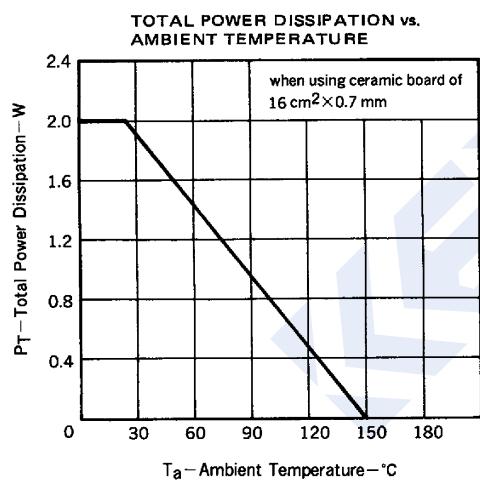
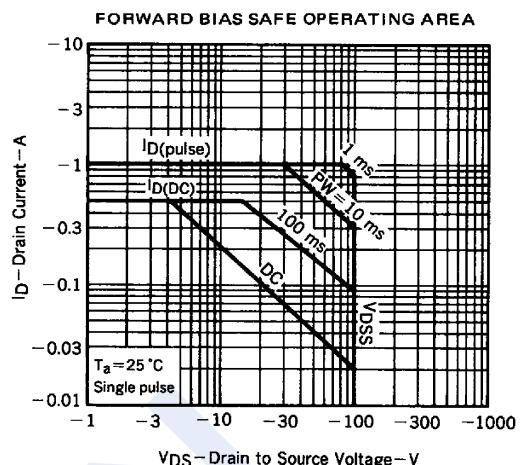
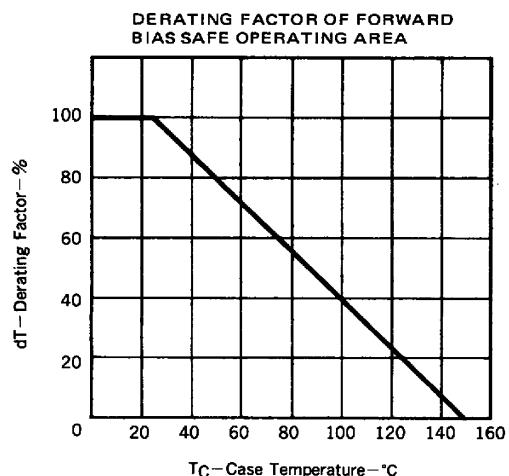
#### ■ Marking

Marking	PP
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## P-Channel MOSFET

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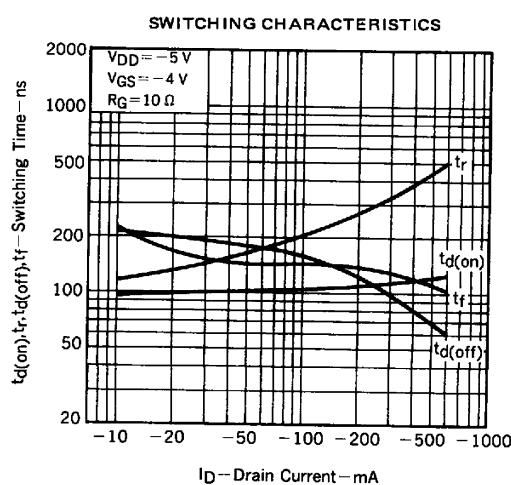
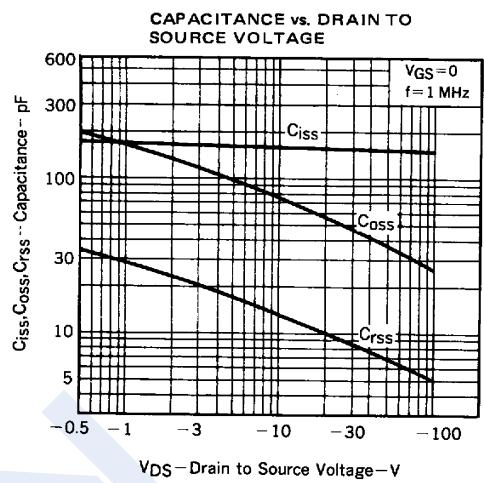
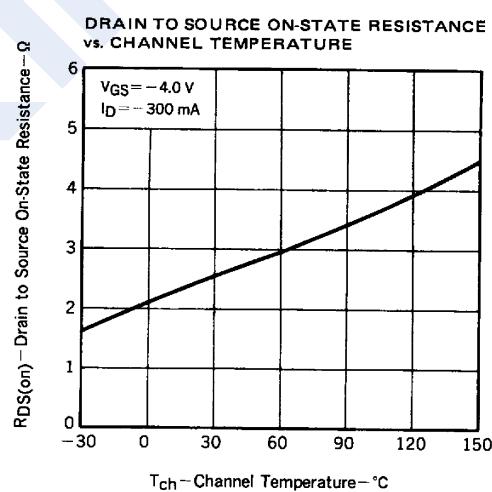
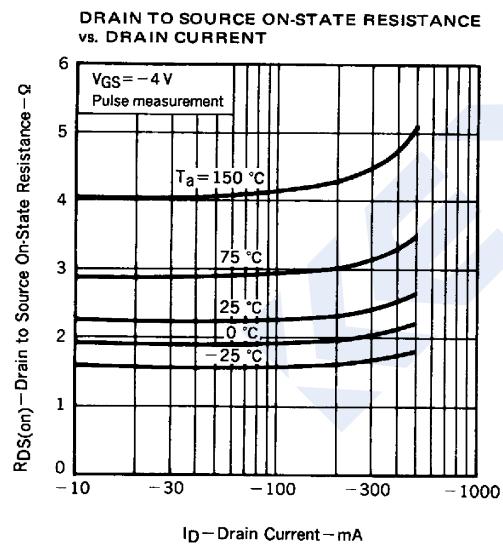
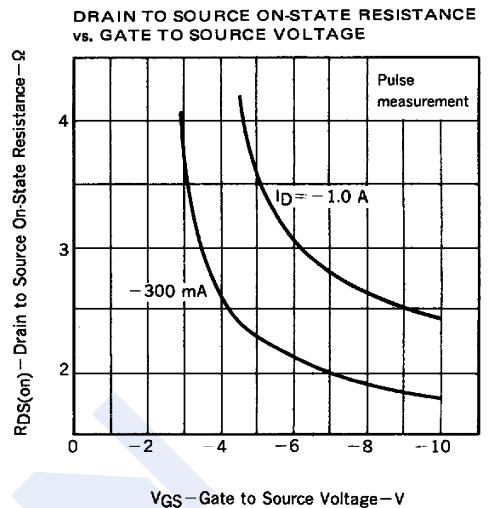
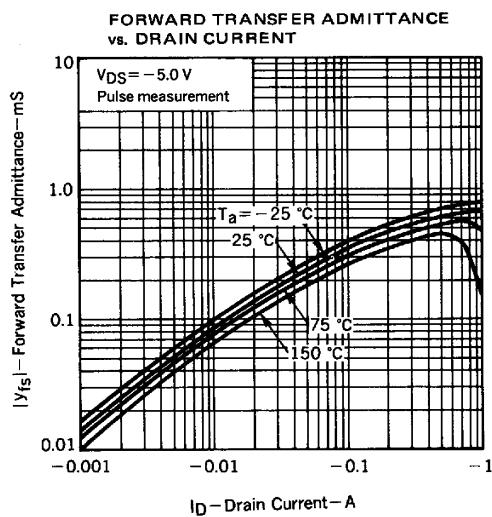
## ■ Typical Characteristics



# P-Channel MOSFET

## 2SJ213

### ■ Typical Characteristics



**P-Channel MOSFET**  
**2SJ213**

■ Typical Characteristics

